

SOT23 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

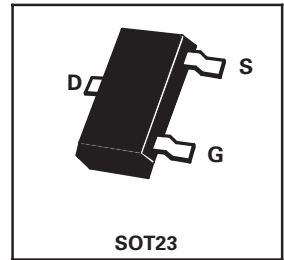
ZVN3320F

ISSUE 3 – DECEMBER 1995

FEATURES

- * 200 Volt V_{DS}
- * $R_{DS(on)} = 25\Omega$

PARTMARKING DETAIL – MU



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	V_{DS}	200	V
Continuous Drain Current at $T_{amb}=25^{\circ}\text{C}$	I_D	60	mA
Pulsed Drain Current	I_{DM}	1	A
Gate-Source Voltage	V_{GS}	± 20	V
Power Dissipation at $T_{amb}=25^{\circ}\text{C}$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV_{DSS}	200		V	$I_D=1\text{mA}, V_{GS}=0\text{V}$
Gate-Source Threshold Voltage	$V_{GS(th)}$	1.0	3.0	V	$I_D=1\text{mA}, V_{DS}=V_{GS}$
Gate-Body Leakage	I_{GSS}		100	nA	$V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$
Zero Gate Voltage Drain Current	I_{DSS}		10 50	μA μA	$V_{DS}=200\text{V}, V_{GS}=0\text{V}$ $V_{DS}=160\text{V}, V_{GS}=0\text{V},$ $T=125^{\circ}\text{C}(2)$
On-State Drain Current(1)	$I_{D(on)}$	250		mA	$V_{DS}=25\text{V}, V_{GS}=10\text{V}$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		25	Ω	$V_{GS}=10\text{V}, I_D=100\text{mA}$
Forward Transconductance(1) (2)	g_{fs}	75		mS	$V_{DS}=25\text{V}, I_D=100\text{mA}$
Input Capacitance (2)	C_{iss}		45	pF	$V_{DS}=25\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$
Common Source Output Capacitance (2)	C_{oss}		18	pF	
Reverse Transfer Capacitance (2)	C_{rss}		5	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		5	ns	$V_{DD} \approx 25\text{V}, I_D=100\text{mA}$
Rise Time (2)(3)	t_r		7	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		6	ns	
Fall Time (2)(3)	t_f		6	ns	

(1) Measured under pulsed conditions. Width=300 μs . Duty cycle $\leq 2\%$ (2) Sample test.

(3) Switching times measured with 50 Ω source impedance and <5ns rise time on a pulse generator

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated:](#)

[ZVN3320FTA](#)